FORM PTO-1449 LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)	ATTY. DOCKET NO. 200210020-1	APPLICATION NO.	CONFIRMATION NO.
	APPLICANT Novet et al.		
	FILING DATE	GROUP	

REFERENCE DESIGNATION **U.S. PATENT DOCUMENTS**

EXAMINER INITIAL		DOCUMENT NUMBER	PUBLICATION DATE	NAME	Pages, Columns, Lines Where Relevant Passages or Figures Appear
MDN	1A	5,894,189	4/13/1999	Ogasawara et al.	
MDN	1B	6,285,118	9/4/2001	Hatai et al.	
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	1K				

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	PUBLICATION DATE	NAME OF PATENTEE OR APPLICANT	Pages/Columns/Lines Where Relevant Passages/Figures Appear	Check if Translation attached
	1L					
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	1N					
	1O					
	1P					

OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

MDN	1Q	Sheng et al., "Efficient and Ballistic Cold Electron Emission from Porous Polycrystalline Silicon Diodes with a Porosity Multilayer Structure", J. Vac. Sci. Technol. B 19(1), Jan/Feb 2001, pp. 64-67.
MDN	1R	Kusunoki et al., "Increasing Emission Current from MIM Cathodes by Using an Ir-Pt-Au Multilayer Top Electrode", IEEE Transactions on Electron Devices, Vol. 47, No. 8, Aug 2000, pp. 1667-1672.
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EXAMINER INITIAL		DOCUMENT NUMBER	PUBLICATION DATE	NAME	Pages, Columns, Lines Where Relevant Passages or Figures Appear
	2A				
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	2J				
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